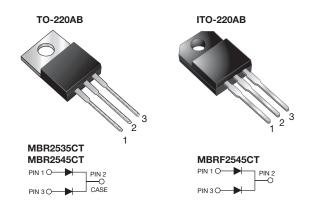


### Vishay General Semiconductor

## **Dual Common Cathode Schottky Rectifier**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 12.5 A				
V <sub>RRM</sub>	35 V, 45 V				
I <sub>FSM</sub>	150 A				
V <sub>F</sub>	0.73 V at 30 A				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB, ITO-220AB				
Diode variation	Common cathode				

#### **FEATURES**

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB

Epoxy meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR2535CT	MBR2545CT	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	35	45		
Working peak reverse voltage		$V_{RWM}$	35	45	V	
Maximum DC blocking voltage		$V_{DC}$	35	45		
Maximum average forward rectified current tot	al device	l .		25	A	
at T <sub>C</sub> = 130 °C	oer diode	I <sub>F(AV)</sub>	12.5			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150		A	
Peak repetitive reverse surge current per diode at t <sub>p</sub> = 2 µs, 1 kHz		I <sub>RRM</sub>	1.0			
Peak non-repetitive reverse energy (8/20 µs waveform) per diode		E <sub>RSM</sub>	25		mJ	
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k $\Omega$		V <sub>C</sub>	25		kV	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs	
Operating junction temperature range		TJ	-65 to +150		°C	
Storage temperature range		T <sub>STG</sub>	-65 to +175			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	15	500	V	



# MBR25xxCT, MBRF25xxCT

# Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	MBR2535CT	MBR2545CT	UNIT	
Maximum instantaneous forward voltage per diode	I <sub>F</sub> = 30 A	T <sub>C</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.82		V	
		T <sub>C</sub> = 125 °C		0.	73		
Maximum instantaneous reverse current at blocking voltage per diode	T <sub>C</sub> = 25 °C		ı (1)	0.2		- mA	
		T <sub>C</sub> = 125 °C	I <sub>R</sub> <sup>(1)</sup>	4	0	ША	

#### Note

 $<sup>^{(1)}</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	UNIT	
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.5	4.5	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2545CT-E3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CT-E3/45	1.99	45	50/tube	Tube		
TO-220AB	MBR2545CT-E3/4W	1.85	4W	50/tube	Tube		

#### Note

<sup>(1) 35</sup> V device available in TO-220AB package only



150

100

75

50

25

0

Peak Forward Surge Current (A)

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### RATINGS AND CHARACTERISTICS CURVES (T<sub>C</sub> = 25 °C unless otherwise noted)

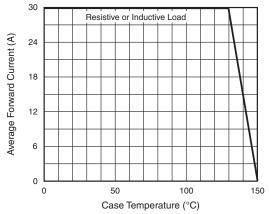
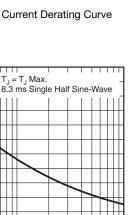


Fig. 1 - Forward Current Derating Curve



100

Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

10

Number of Cycles at 60 Hz

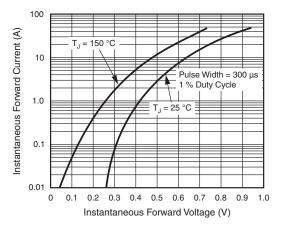


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

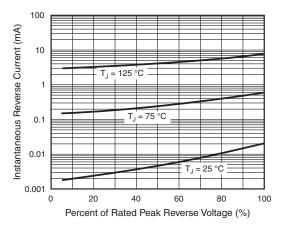


Fig. 4 - Typical Reverse Characteristics Per Diode

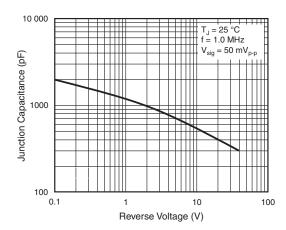


Fig. 5 - Typical Junction Capacitance Per Diode

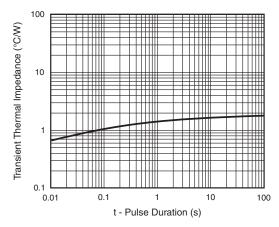
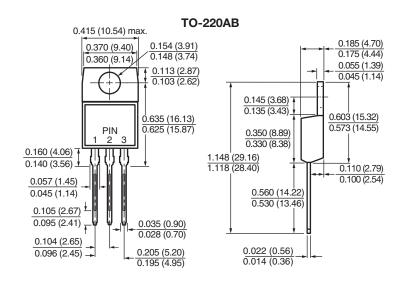


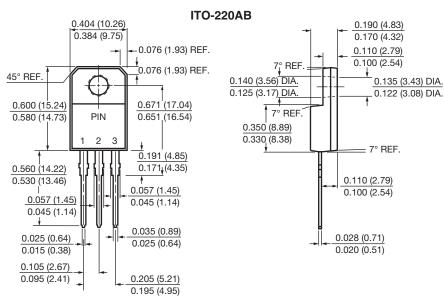
Fig. 6 - Typical Transient Thermal Impedance Per Diode



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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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